**Limited Tender** 

#### Government of India Department of Atomic Energy BHABHA ATOMIC RESEARCH CENTRE Beam Technology Development Group Mumbai-400085

Ref: 23751/2021/28PTD.

Date: 13/12/2021

#### Sub: Minor Fabrication of Optical Power Measuring System

#### DUE DATE: 25<sup>th</sup> December 2021

- 1. Quotations are invited for the fabrication, installation, testing and commissioning job as per the enclosed job details.
- The quotations must reach. Head, Laser & Plasma Technology Division by above mentioned due date and must be sent in a sealed envelope <u>super-scribed</u> with the above reference number and due date given above.
- **3.** As this is a limited tender, the suppliers who are contacted by the purchaser may only quote for this work.
- 4. The address on the envelope should read

(Attn. Pooja Chakraborty) To, Head, Laser & Plasma Technology Division BARC, Mumbai - 400 085

- 5. The quotation must be submitted on printed letter head of the company and should contain **PAN** and **GST** number else the quotation shall be rejected.
- 6. The finished components, fabricated at vendors' works, shall be dispatched for installation and commissioning at site only after the approval of our engineer. Necessary inspection facilities should be provided to our engineers during fabrication at bidder's premises
- 7. Head Laser and Plasma Technology Division, BARC reserves the right to accept or reject any or all quotations without assigning any reason.
- 8. The drawing for the quoted items should be included with quotations.
- 9. Sealed quotation shall be received on or before 25<sup>th</sup> December 2021

#### through Speed post/ Registered post of Indian Postal Services only.

- 10. BARC reserves the right to reject any or all tenders/ applications without assigning any reason thereof.
- 11. For any further clarification Pooja Chakraborty, L&PTD, (Ext No. 25068/20214) may be contacted.

Yours faithfully,

Head L&PTD M. L. Moscarenhas जन्मप/Head लेसा अंड प्लाच्मा प्रोद्योगिकी प्रभाग Laser & Plasma Tachnology Division भा.प.अ. केंद्र/B.A.R.C.

# Job Detail

# **Technical Specification of Power Measurement System**

# 1. Scope of work:

It includes fabrication of Optical Power measuring system to measure the optical power levels of Visible and IR lasers.

# 2. Components:

SL. NO.	COMPONENTS		QTY	
1.	Laser Power Meter with Photodiode sensor		1 set	
2.	Optical Lens	Focal length = 20 mm Focal length = 22 mm	5 units 5 units	
		Focal length = $18$ mm	5 units	
3.	InGaAs Photodiode with FC/PC receptacle		20 units	

## 2.1 LASER POWER METER Qty 1 set

- 1) Accessories and software
- 2) Photodiode Sensor (Visible Range) Model No: PD300-1W with FC connector
- 3) Photodiode Sensor (IR Range) Model No: PD300-IRG with FC connector
- 4) Display Unit Model No: Vega

## DETAIL TECHNICAL SPECIFICATION

#### I) <u>Power Meter:</u>

- i) Measurement: Energy and Power
- ii) Display Features Required: TFT 320 x 240-pixel graphics LCD display. Large 16mm digits. Bar graph and chart display. Display of parameters like energy, Power density, Exposure, energy, average, exposure, frequency
- iii) **Outputs**: USB, RS232 and user selectable 1, 2, 5 and 10Volt full scale analog output
- iv) Screen Refresh Rate: 15 Hz or better
- v) **Include Battery specs**: Rechargeable NiMH batteries with typically 15-20 hours between charges
- vi) **Data Handling**: On Board storage of up to 250,000 data points Data transmission rate of 500 points/s or better to PC. RS232 baud rate of 38400
- vii) Sensor Feature: Compatible with Photodiode Sensor-both IR and visible range (Specification mentioned below).

#### II) Accessories and software for Power Meter:

- i) USB cable for Field upgrade and PC interfacing
- ii) RS232 Cable for data transfer
- iii) Battery Charger
- iv) Analog Output Connector
- v) Power Meter SDK and drivers for PC interfacing and data display

# III) <u>Photodiode Sensor (Visible Range):</u>

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1.	Detector Type	Silicon		
2.	Aperture	10 mm × 10 mm		
3.	Filter Option	Yes		
4.	Filter Mode	Filter OUT	Filter IN	
5.	Spectral Range(nm):	400-1100		
6.	Power Range	0.5nW-30mW	200µW-1W	
7.	Power Scales	30mW to 30nW	1W to 30mW	
8.	Resolution	>0.01 nW		
9.	Accuracy (filter Out):	±.3% or better		
10.	Damage Threshold	10 W/cm <sup>2</sup>		
11.	Maximum Pulse Energy	2 μJ	100 µJ	
12.	Noise Level for filter out	20 pW		
13.	Response Time with Meter	0.2 sec or better		
14.	Beam Position Dependence	±2 %		
15.	Fiber Adapter	FC/PC		

## IV) Photodiode Sensor (IR Range):

1.	Detector Type	InGaAs		
2.	Aperture	5 mm Dia		
3.	Filter Option	Yes		
4.	Filter Mode	Filter Out	Filter In	
5.	Spectral Range(nm):	800-1700		
6.	Power Range	10pW-800µW	150µW-	
	8		200mW	
7.	Power Scales	800µW to	300 mW to	
		800pW	3mW	
8.	Resolution	> 0.1 pW	>1nW	
9.	Accuracy (filter Out):	$\pm 3\%$ or better		
10.	Damage Threshold	$5 \text{ W/cm}^2$	$50 \text{ W/cm}^2$	
11.	<b>Maximum Pulse Energy</b>	1 μJ	100 µJ	
12.	Noise Level for filter out	±300 fW		
13.	<b>Response Time with Meter</b>	0.2 sec or better		
14.	Beam Position	±1 %		
	Dependence			
15.	Fiber Adapter	FC/PC		

#### **2.2 OPTICAL LENS:**

# A) Optical lens of focal length 20 mm units

Qty-5

- i) Plano convex lens of effective Focal length = 20mm, **diameter= 9mm**
- ii) Coating Specification: Ravg <1.25% @ 400-700nm
- iii) Surface Quality: 40-20
- iv) Irregularity (P-V) @ 632.8nm:  $\lambda/4$
- v) Centering (arcmin): <=1
- vi) Edge Thickness ET (mm): 1.5
- vii) Clear Aperture CA (mm): 6.4mm NA= 0.16
- viii) Typical Energy Density Limit: 500mJ/cm2 @ 633nm, 10ns
- ix) Coating: Single layer MgF2 (400-700nm)
- x) Substrate: Fused silica
- xi) Power (P-V) @ 632.8 nm: 1.5λ
- xii) Focal Length Tolerance (%): +/-1
- xiii) Center Thickness CT (mm): 2.68 +/- 0.2
- xiv) Radius R1 (mm):9.17

xv) f/#:2.2

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### B) Optical lens of focal length 22 mm -

- i) Plano convex lens of effective Focal length = 22mm, **diameter= 9mm**
- ii) Coating Specification: Ravg <1.25% @ 400-700nm
- iii) Surface Quality: 40-20
- iv) Irregularity (P-V) @ 632.8nm:  $\lambda/4$
- v) Centering (arcmin): <=1
- vi) Edge Thickness ET (mm): 1.5
- vii) Clear Aperture CA (mm): 6.4mm NA= 0.16
- viii) Typical Energy Density Limit: 500mJ/cm2 @ 633nm, 10ns
- ix) Coating: Single layer MgF2 (400-700nm)
- x) Substrate: Fused silica
- xi) Power (P-V) @ 632.8 nm: 1.5λ
- xii) Focal Length Tolerance (%): +/-1
- xiii) Center Thickness CT (mm): 2.68 +/- 0.2
- xiv) Radius R1 (mm):9.17
- xv) f/#:2.2

## C) Optical lens of focal length 18 mm

Qty 5

- i) Plano convex lens of effective Focal length = 18mm, **diameter= 9mm**
- ii) Coating Specification: Ravg <1.25% @ 400-700nm
- iii) Surface Quality: 40-20
- iv) Irregularity (P-V) @ 632.8nm:  $\lambda/4$
- v) Centering (arcmin): <=1
- vi) Edge Thickness ET (mm): 1.5
- vii) Clear Aperture CA (mm): 6.4mm NA= 0.16
- viii) Typical Energy Density Limit: 500mJ/cm2 @ 633nm, 10ns
- ix) Coating: Single layer MgF2 (400-700nm)
- x) Substrate: Fused silica
- xi) Power (P-V) @  $632.8 \text{ nm}: 1.5\lambda$
- xii) Focal Length Tolerance (%): +/-1
- xiii) Center Thickness CT (mm): 2.68 +/- 0.2
- xiv) Radius R1 (mm):9.17
- xv) f/#:2.2

#### 2.3 InGaAs PHOTODIODE WITH FC/PC RECEPTACLE

**Detector Type** InGaAs 1. 2. **Active Area Diameter** 120 µm 3. Spectral Range(nm) 800-1700 4. Responsivity @ 1550nm 0.95 A/W(maximum) 0.9 A/W(maximum) Responsivity @ 1310nm 5. Junction Capacitance @ 5V reverse 1pF 6. voltage <10<sup>-14</sup> W/Hz<sup>-0.5</sup> 7. Noise Equivalent Power(NEP) 8. **Maximum Forward Current** >5 mA 9. **Maximum Reverse Current** 2 mA or more 10. Dark Current @ -5V <5 nA Rise Time/Fall time @ -5V 11. <1 nsec 12. TO 46 with lensed cap Package FC/PC 13. **Fiber Adapter** 14. **ROHS** compliant Yes

#### 2. Packing and Forwarding

These items are to be packed for damage free transport.

### 3. Inspection and Acceptance Criteria

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- a. All fabricated components shall be inspected by purchaser.
- b. The items after fabrication will be delivered to BARC only after final inspection. The complete order has to be supplied within 60 days of the issue of the purchase order. The material is to be supplied at 1-359 H, Modular lab., BARC Trombay. Shorter delivery period will be preferred.
- c. The circuit diagram of both PCBs will be provided.
- d. The delivery shall be in good quality packing materials to avoid any type of damage during transit.
- e. The material shall cover the guarantee/warrantee of minimum one year against any form of defect and quality degradation after installation on site.

Qty 20